LISTING OF CLAIMS

This listing of claims will replace all prior versions and listings of claims in this application. Added text is indicated by <u>underlining</u>, and deleted text is indicated by <u>strikethrough</u>. Changes are identified by a vertical bar in the margin.

1. (currently amended) An apparatus for measuring radiant intensity of a photolithographic illumination source in a photolithography projection imaging system, the apparatus comprising:

a plurality of discrete imaging objectives, each capable of imaging to a corresponding field point, thereby imaging a plurality of field points; and

a common imaging surface for the plurality of discrete imaging objectives, wherein each of the plurality of field points is imaged on the common imaging surface;

wherein the discrete imaging objectives have sufficient resolution <u>such that</u> the apparatus produces a to permit reconstruction of a radiant intensity profile of the illumination source.

- 2. (original) The apparatus as defined in Claim 1, wherein the intensity profile is reconstructed from measurement of radiant intensity at the field points.
- 3. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a plano convex lens.
- 4. (previously presented) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a computer generated hologram element.
- 5. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises an aspherically corrected lens.

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- 6. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a computer generated hologram integral with a reticle top surface.
- 7. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a micro imaging objective.
- 8. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a multi-element imaging objective.
- 9. (original) The apparatus of Claim 1, wherein one or more of the discrete imaging objectives comprises a reflective computer generated holographic plate.
- 10. (original) The apparatus of Claim 1, wherein said common imaging surface comprises a reticle face.
- 11. (original) The apparatus of Claim 1, wherein said common imaging surface comprises a plane located beyond a reticle face.
- 12. (original) The apparatus of Claim 1, wherein said common imaging surface comprises a plane located before a reticle face.
- 13. (original) The apparatus of Claim 1, wherein the discrete imaging objectives fit within a reticle/pellicle envelope.
- 14. (original) The apparatus of Claim 1, wherein the discrete imaging objectives can be placed in an illuminator beamtrain such that the common imaging surface lies at a reticle conjugate imaging plane.

- 15. (previously presented) The apparatus of Claim 1, further comprising a common mounting for the plurality of imaging objectives.
- 16. (original) The apparatus of Claim 15, wherein the common mounting comprises a projection imaging tool.
- 17. (original) The apparatus of Claim 15, wherein the common mounting comprises a support plate.
- 18. (original) The apparatus of Claim 1, wherein the discrete imaging objectives can be placed in an illuminator beamtrain such that the common imaging surface lies at a reticle conjugate imaging plane.
- 19. (currently amended) A projection imaging system comprising: an illuminator comprising a light source that generates a radiant intensity profile and produces an illuminator beamtrain;
- a multiple field imaging objective in optical communication with the light source;
- a projection imaging optic distal the multiple field imaging objective; and an electronic sensor array, wherein the multiple field imaging objective images the radiant intensity profile onto a plane optically conjugate to the electronic sensor array via the projection imaging optic with sufficient resolution such that the system produces a to permit reconstruction of the radiant intensity profile.
- 20. (previously presented) The apparatus of Claim 19, further comprising a reticle table that separates a reticle from the projection imaging optic.
- 21. (original) The apparatus of Claim 19, wherein the electronic sensor array comprises an imaging optic that relays the plane to the sensor array.

- 22. (original) The apparatus of Claim 19, wherein multiple field imaging objective comprises a reticle having one or more computer generated holograms written on its face.
- 23. (currently amended) A projection imaging system comprising:

an illuminator comprising a light source, a reflective substrate, and a reflective reticle, wherein the light source projects a plurality of light rays toward the reflective substrate, which reflects the light rays toward the reflective reticle; and

a multiple field imaging objective in optical communication with the reflective reticle, wherein the plurality of rays are incident on the multiple field imaging objective;

wherein the multiple field imaging objectives have sufficient resolution <u>such</u> that the system produces a to permit reconstruction of a radiant intensity profile of the illumination source.

- 24. (original) The projection imaging system of Claim 23, wherein the source image lies in a plane distal to the reticle.
- 25. (original) The projection imaging system of Claim 23, wherein the reflective substrate comprises a folding mirror.
- 26. (original) The projection imaging system of Claim 23, wherein the reflective substrate comprises one or more computer generated holograms.
- 27. (original) The projection imaging system of Claim 26, wherein the reflective substrate comprises at least two computer generated holograms separated by one or more non-reflective regions.
- 28. (original) The projection imaging system of Claim 23, wherein the reflective reticle comprises a reflective coating with modulated reflectivity.

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29. (currently amended) A projection imaging system comprising:

an illuminator comprising a light source, a reflective substrate, and a reflective reticle, wherein an illuminator beamtrain is projected toward the reflective substrate that includes a multiple in-situ imaging objective, and is reflected toward the reflective reticle; and

a common imaging surface where the radiant intensity of the beamtrain is recorded at multiple field points;

wherein the multiple in-situ imaging objectives have sufficient resolution <u>such</u> that the system produces a to permit reconstruction of a radiant intensity profile of the illuminator.

- 30. (original) A projection imaging system as defined in Claim 29, wherein the insitu imaging objective is a computer generated hologram.
- 31. (original) A projection imaging system as defined in Claim 29, wherein the insitu imaging objective is an asphere.
- 32. (currently amended) A projection imaging system comprising: a multiple field imaging objective;

an aperture blade located at a distance that coincides with a reticle conjugate imaging plane associated with the multiple field imaging objective;

a source relay in optical communication with the multiple field imaging objective; and

a reticle;

wherein the source relay optic images the multiple field objective image formed at the reticle conjugate imaging plane onto the reticle with sufficient resolution such that the system produces a to permit reconstruction of a radiant intensity profile of an illuminator.

- 33. (original) The projection imaging system of Claim 32, wherein the multiple field imaging objective comprises multiple elements.
- 34. (currently amended) A projection imaging system comprising:

a multiple field imaging objective located so that the imaging surface of the multiple field imaging objective coincides with a conjugate imaging plane of a reticle;

an aperture blade located at the reticle conjugate imaging plan;

a source relay optic in optical communication with the reticle so as to relay images of the multiple field imaging objective formed at the reticle conjugate imaging plane onto a substrate with sufficient resolution such that the system produces a to permit reconstruction of a radiant intensity profile of an illuminator.

- 35. (original) The projection imaging system of Claim 34, wherein the multiple field imaging objective comprises multiple elements.
- 36. (withdrawn) A process for measuring the radiant intensity of an illuminator beamtrain in a projection lithography tool comprising:

loading a multiple field in-situ imaging objective with sufficient resolution to permit reconstruction of a radiant intensity profile of an illuminator into the projection lithography tool;

exposing a recording substrate to multiple doses of light through the in-situ imaging objective;

developing the substrate and measuring the substrate to determine exposed regions versus dose; and

reconstructing the radiant intensity profile of the illuminator using the measurements.

37. (withdrawn) A process as described in Claim 36, wherein the projection lithography tool comprises a stepper, a one dimensional scanner, a two dimensional scanner, an EUV scanner, an EPL machine, or an image side immersion lens.

- 38. (withdrawn) A process as described in Claim 36, wherein the recording substrate comprises a silicon wafer, a flat panel, a circuit board, or a wafer mounted electronic sensor.
- 39. (withdrawn) A process for measuring the radiant intensity of an illuminator in a projection lithography tool comprising:

exposing a recording substrate with a multiple field in-situ imaging objective with sufficient resolution to permit reconstruction of a radiant intensity profile of an illuminator; and

reconstructing the radiant intensity profile of the illuminator using measurements of the exposed substrate.

- 40. (withdrawn) A process as defined in Claim 39, wherein the substrate is a silicon wafer.
- 41. (withdrawn) A process for measuring the radiant intensity of an illuminator beamtrain in a projection lithography tool, the process comprising:

loading a multiple field in-situ imaging objective with sufficient resolution to permit reconstruction of a radiant intensity profile of an illuminator into the projection lithography tool;

providing an electronic sensing array, wherein the electronic sensing array is in optical communication with the imaging objective;

exposing the electronic sensing array to an illuminator beamtrain through the imaging objective;

recording the electronic sensing array output; and

reconstructing the radiant intensity profile of the illuminator beamtrain using measurements of the sensing array.

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42. (withdrawn) A process for producing a photolithographic chip mask work from a photolithography projection imaging system, the method comprising: projecting a desired mask work reticle in the projection imaging system;

measuring the radiant intensity of an illuminator beamtrain in the projection lithography system by performing operations comprising: loading a multiple field in-situ imaging objective with sufficient resolution to permit reconstruction of a radiant intensity profile of the illuminator beamtrain into a projection lithography tool of the projection imaging system;

exposing a recording substrate to multiple doses of light through the in-situ imaging objective;

developing the substrate and measuring the substrate to determine exposed regions versus dose;

reconstructing the radiant intensity profile of the illuminator beamtrain using the measurements; and

controlling production of chip mask works through adjustment of projection imaging system in accordance with the reconstructed radiant intensity profile of the illuminator beamtrain.

- 43. (withdrawn) A process as described in Claim 42, wherein the projection lithography tool comprises a stepper, a one dimensional scanner, a two dimensional scanner, an EUV scanner, an EPL machine, or an image side immersion lens.
- 44. (withdrawn) A process as described in Claim 42, wherein the recording substrate comprises a silicon wafer, a flat panel, a circuit board, or a wafer mounted electronic sensor.
- 45. (withdrawn) A microelectronic chip production system comprising: a production system controller that operates the system; and a photolithographic projection imaging system comprising:

a scanning controller that controls a scanner of the projection imaging system;

a plurality of discrete imaging objectives, each capable of imaging to a corresponding field point, thereby imaging a plurality of field points wherein the plurality of discrete imaging objectives have sufficient resolution to permit reconstruction of a radiant intensity profile of an illuminator;

a common imaging surface for the plurality of discrete imaging objectives, wherein each of the plurality of field points is imaged on the common imaging surface;

a common mounting for the plurality of imaging objectives; and a process controller that measures radiant intensity of a photolithographic illumination source in the photolithography projection imaging system and adjusts operation of the projection imaging system in accordance with the measured radiant intensity.

46. (withdrawn) A method of controlling a photolithographic projection scanner comprising:

exposing a recording substrate with a multiple field in-situ imaging objective wherein the multiple in-situ imaging objectives have sufficient resolution to permit reconstruction of a radiant intensity profile of an illuminator;

reconstructing the radiant intensity profile of the illuminator using measurements of the exposed substrate; and

adjusting the scanner in accordance with the reconstructed radiant intensity profile so as to minimize variations in the radiant intensity profile of the scanner.

47. (withdrawn) A method as defined in Claim 46, wherein the substrate comprises a semiconductor wafer.